

ON Semiconductor®

FDMS9408-F085 N-Channel PowerTrench[®] MOSFET

40 V, 80 A, 1.8 m Ω

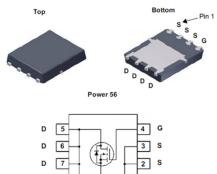
Features

- Typical $R_{DS(on)}$ = 1.5 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 68 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





1 S FDMS9408-F085 N-Channel PowerTrench[®] MOSFET

8 D **MOSFET Maximum Ratings** T_J = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
1	Drain Current - Continuous (V _{GS} =10) (Note 1)	$T_C = 25^{\circ}C$	80	^	
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	143	mJ	
D	Power Dissipation		214	W	
PD	Derate Above 25°C		1.43	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.7	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

1: Current is limited by bondwire configuration.

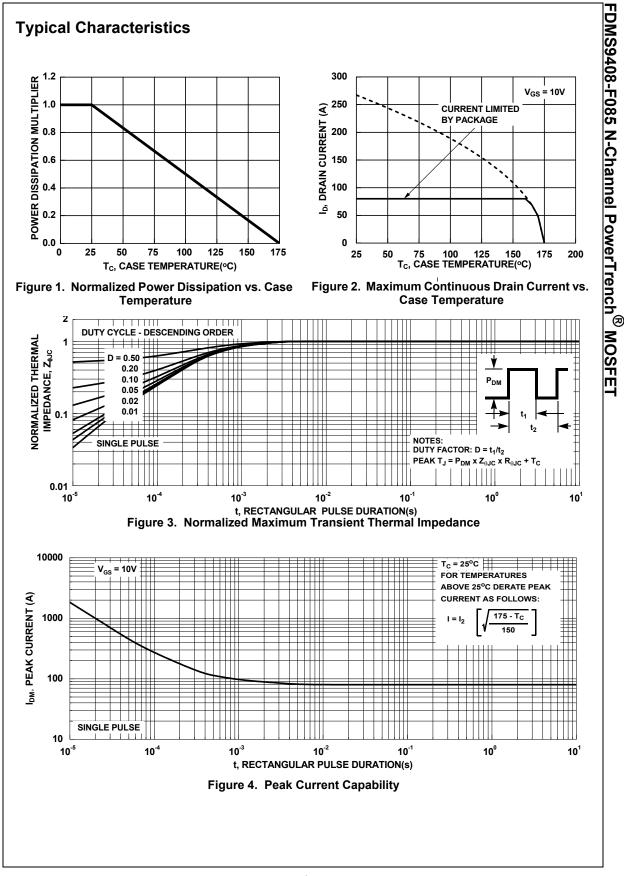
2: Starting $T_J = 25^{\circ}$ C, L = 70uH, $I_{AS} = 64$ A, $V_{DD} = 40$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder moduling surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

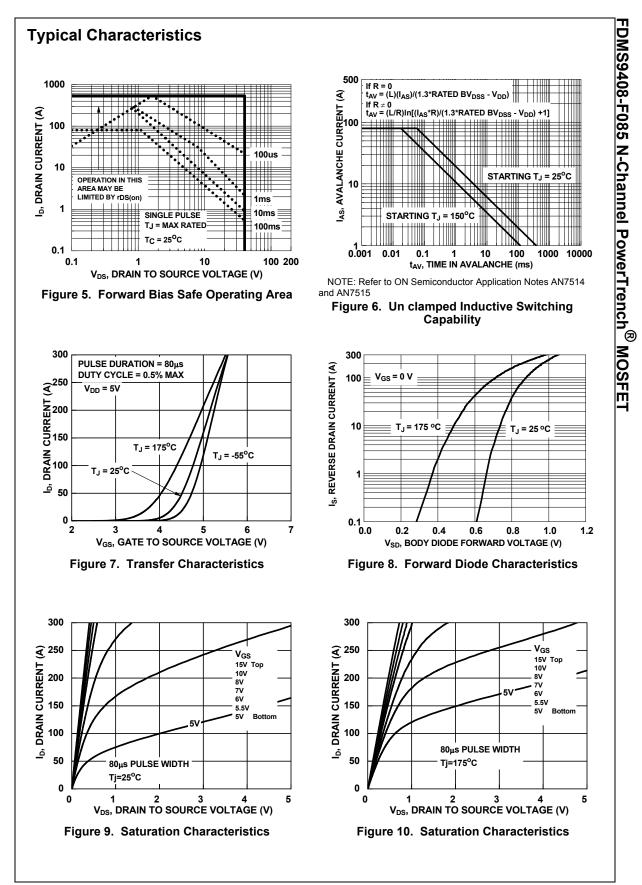
Package Marking and Ordering Information

Device	Marking	Device	Package	Reel Size	Tape Width	Quantity
FDM	S9408	FDMS9408-F085	Power56	13"	12mm	3000units

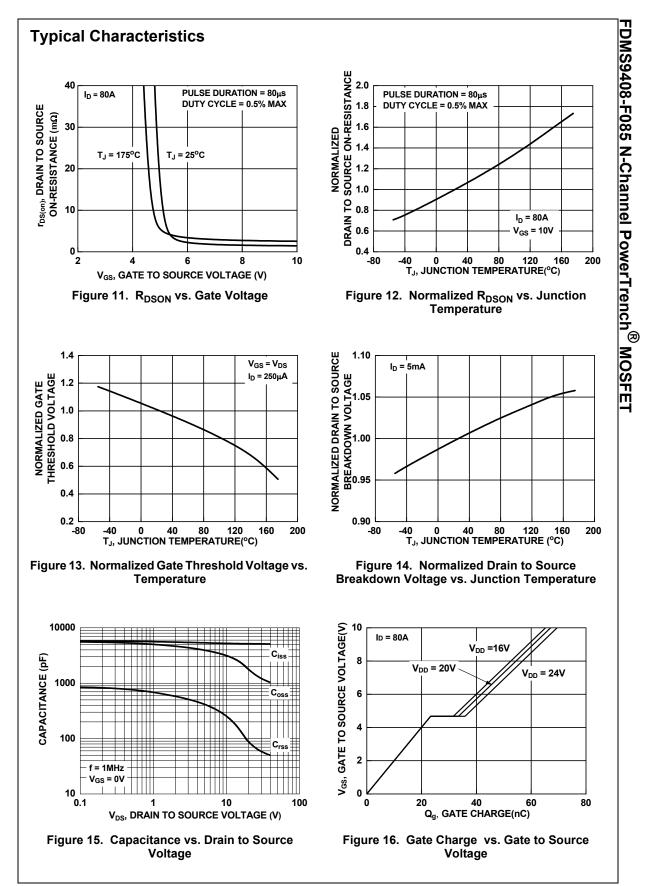
Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	aracteristics							
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	_	V	
		$V_{DS} = 40V$. $T_1 = 25^{\circ}C$			-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$	-	'5 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
On Cha	racteristics							
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.0	4.0	V	
• GS(th)	-	$I_D = 80A, T_J = 25^{\circ}$			-	1.5	1.8	mΩ
R _{DS(on)}	Drain to Source On Resistance		$T_{1} = 175^{\circ}C$ (Note 4)		-	2.5	3.0	mΩ
C _{iss}	Input Capacitance	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz		-	5150	-	pF	
C _{oss}	Output Capacitance			-	1770	-	pF	
C _{rss}	Reverse Transfer Capacitance	6 ANUL-		-	89	-	pF	
R _g	Gate Resistance	f = 1MHz		-	2.8	-	Ω	
Q _{g(ToT)}	Total Gate Charge			V _{DD} = 32V	-	68 9.3	92 14	nC nC
Q _{g(th)}	Threshold Gate Charge Gate-to-Source Gate Charge			-	9.3	-	nC	
Q _{gs} Q _{gd}	Gate-to-Drain "Miller" Charge			_	-	12	-	nC
Switchi	ng Characteristics							
t _{on}	Turn-On Time				-	-	51	ns
t _{d(on)}	Turn-On Delay	V_{DD} = 20V, I _D = 80A, V _{GS} = 10V, R _{GEN} = 6Ω			-	19	-	ns
t _r	Rise Time				-	20	-	ns
t _{d(off)}	Turn-Off Delay			6Ω	-	41	-	ns
t _f	Fall Time				-	19	-	ns
t _{off}	Turn-Off Time				-	-	79	ns
Drain-S	ource Diode Characteristics							
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V			-	-	1.25	V
	-	I _{SD} = 40A, V _{GS} = 0V			-	-	1.2	V
+	Reverse-Recovery Time Reverse-Recovery Charge	I _F = 80A, dI _{SD} /dt = 100A/μs V _{DD} = 32V		-	74 83	96 108	ns nC	
t _{rr} Q _{rr}					-	00	100	no



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